PDFN5×6 N

N-Channel MOSFET in a PDFN5×6 Plastic Package.

VDS(V)=30 V ID=80A

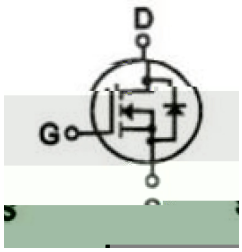
$R_{DS(ON)}$@10V≤4.5mΩ(Typ.3.7mΩ)

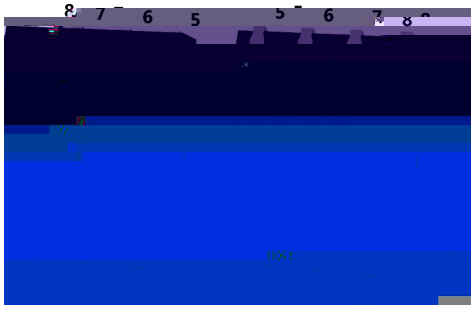
$R_{DS(ON)}$@4.5V≤6mΩ(Typ.5.1mΩ)

HF Product.

MB/NB/UMPC/VGA Buck -

Battery Management,High Frequency Point-of-Load Synchronous Buck Conventer for MB/NB/UMPC/VGA,Networking DC-DC Power System,Load Switch.





PIN1 2 3 S PIN4 G PIN5 6 7 8 D

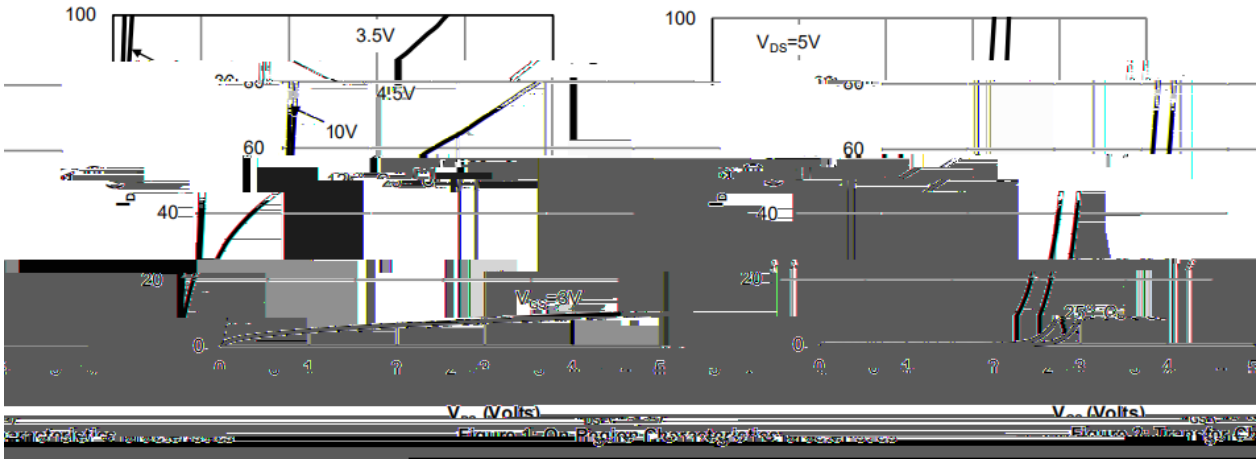
Pin	极性
1	S
2	S
3	S
4	G
5	D
6	D

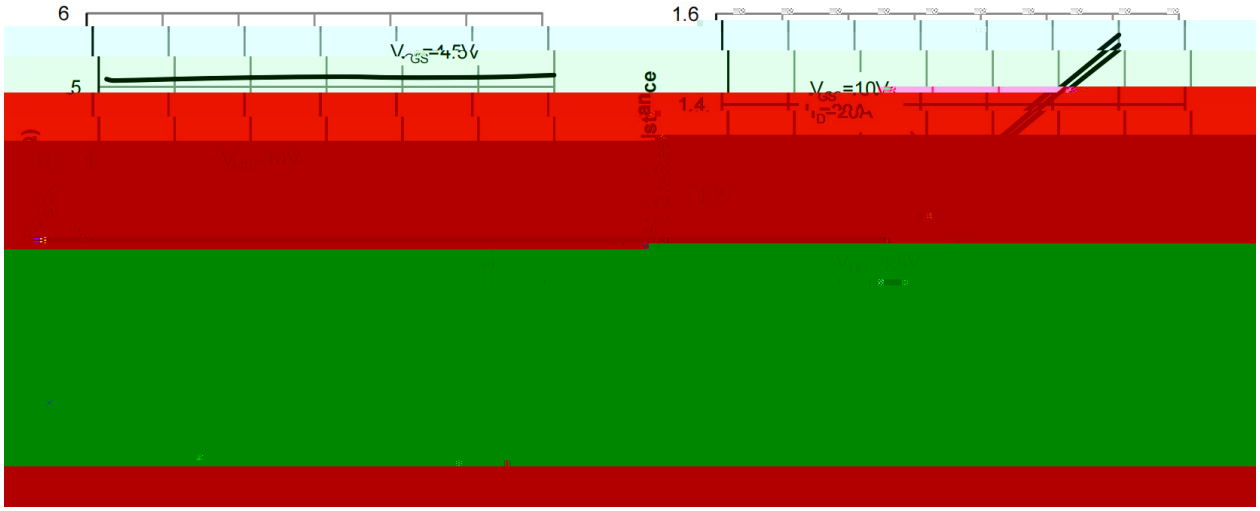
See Marking Instructions.

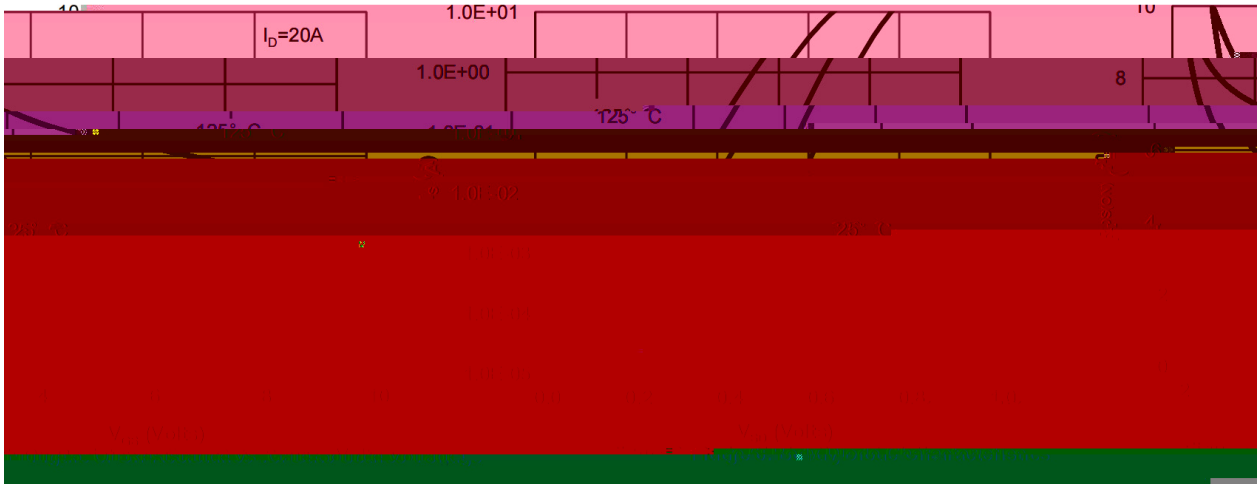
Parameter		Symbol	Rating	Unit
Drain-Source Voltage		V_{DS}	30	V
Drain Current - Continuous		I_D	80	A
Drain Current - Continuous		I_D(T_c=70)	36	A
Drain Current – Pulsed		I_{DM}	168	A
Gate-Source Voltage		V_{GS}	± 20	V
Power Dissipation		P_D(T_c=25)	45	W
Single Pulse Avalanche Energy(L=0.5mH)		E_{AS}	274	mJ
Avalanche Current(L=0.5mH)		I_{AS}	28	A
Junction and Storage Temperature Range		T_j, T_{stg}	-55 to 150	
Thermal resistance, junction - ambient	t ≤ 10s	$R_{\theta JA}$	25	/ W
	Steady-State		55	
Thermal resistance, junction - case	Steady-State	$R_{\theta JC}$	2.8	

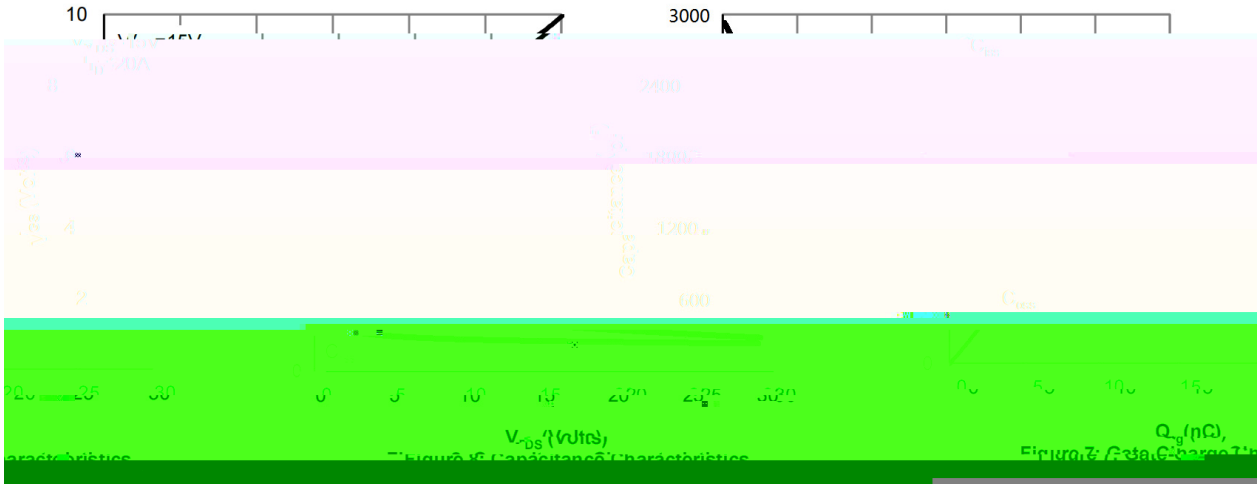
Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Drain-Source Breakdown Voltage	BV_{DSS}	I_D=250uA, V_{GS}=0V	30	33		V
Zero Gate Voltage Drain Current	I_{DSS}	V_{DS}=30V, V_{GS}=0V			1.0	uA
Gate-Body leakage current	I_{GSS}	V_{DS}=0V, V_{GS}= ±20V			±100	nA
Gate Threshold Voltage	$V_{GS(th)}$	V_{DS}=V_{GS}, I_D=250uA	1	1.5	3	V
Static Drain-Source On-Resistance	$R_{DS(ON)}$	V_{GS}=10V, I_D=20A		3.7	4.5	mΩ
		V_{GS}=4.5V, I_D=10A		5.1	6	
Diode Forward Voltage	V_{SD}	I_S=1A, V_{GS}=0V			1.2	V
Input Capacitance	C_{iss}	V_{DS}=25V V_{GS}=0V f=1.0MHz		2500		pF
Output Capacitance	C_{oss}			280		
Reverse Transfer Capacitance	C_{rss}			210		
Gate resistance	R_g	V_{GS}=0V V_{DS}=0V f=1MHz		3.3		q
Total Gate Charge	$Q_{g(10V)}$	V_{GS}=10V, V_{DS}=15V, I_D=20A		30		nC
Total Gate Charge	$Q_{g(4.5V)}$			13.5		
Gate Source Charge	Q_{gs}			5.5		
Gate Drain Charge	Q_{gd}			3.5		

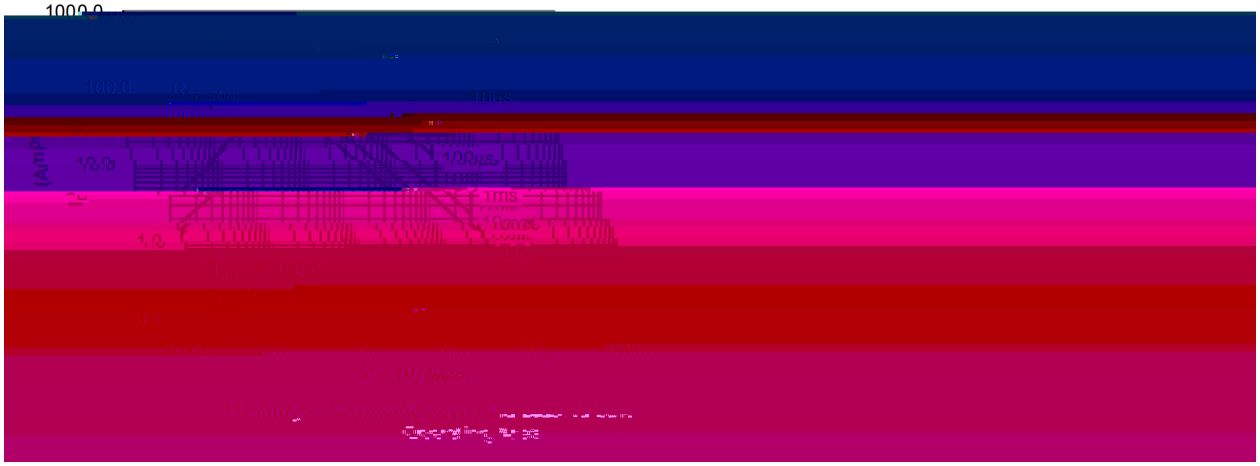
Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Turn-On Delay Time	$t_{d(on)}$	V_{GS}=10V V_{DS}=15V R_L=0.75Ω R_{GEN}=3Ω		8		ns
Turn-On Rise Time	t_r			3		
Turn-Off Delay Time	$t_{d(off)}$			34		
Turn-Off Fall Time	t_f			5.5		

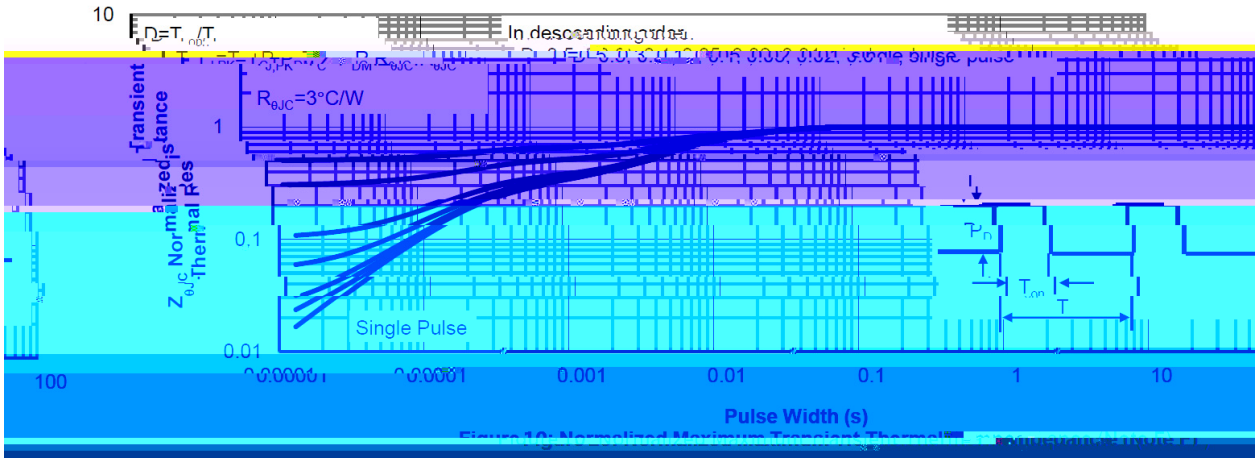

100
3.5V
4.5V
10V
60
40
20
0
100
V_{DS}=5V
60
40
20
0


6
5
1.6
1.4


I_D=20A
1.0E+01
1.0E+00
125° C
8

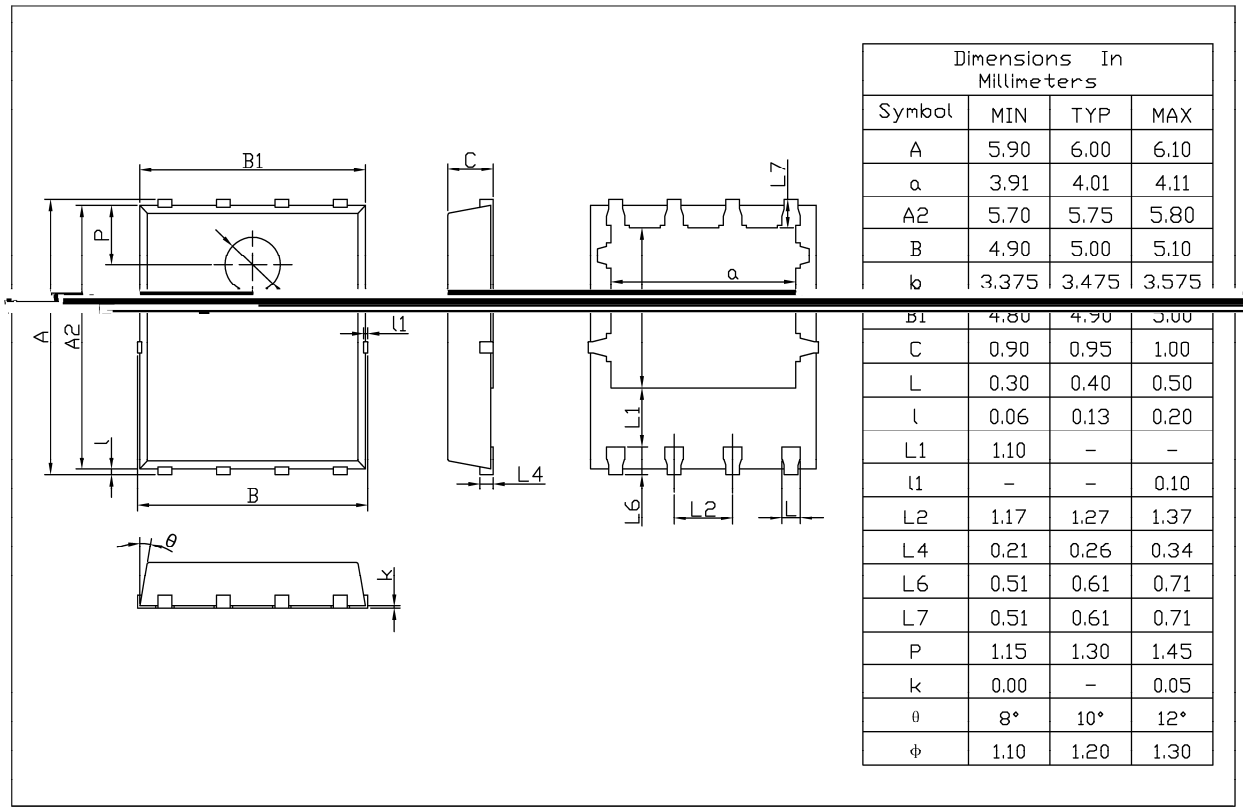

10
3000
2400
1200
600
Capacitance (pF)
V_{DS} (Volts)
Q_g (nC),


1000.0
100.0
10ms
1ms
100μs
10μs
1.0
0.1


10
D=T$_{on}$/T
In descending order
R$_{θJC}$=3°C/W
1
0.1
0.01
Single Pulse
Transient Thermal Resistance
Z$_{θJC}$ Normalized
P$_D$
T$_{on}$
T
100
0.0001
0.001
0.01
0.1
1
10
Pulse Width (s)

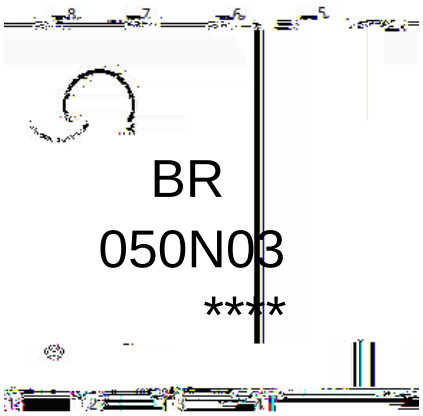
PDFN5X6

Unit:mm



Dimensions In Millimeters			
Symbol	MIN	TYP	MAX
A	5.90	6.00	6.10
a	3.91	4.01	4.11
A2	5.70	5.75	5.80
B	4.90	5.00	5.10
b	3.375	3.475	3.575
B1	4.80	4.90	5.00
C	0.90	0.95	1.00
L	0.30	0.40	0.50
l	0.06	0.13	0.20
L1	1.10	–	–
l1	–	–	0.10
L2	1.17	1.27	1.37
L4	0.21	0.26	0.34
L6	0.51	0.61	0.71
L7	0.51	0.61	0.71
P	1.15	1.30	1.45
k	0.00	–	0.05
θ	8°	10°	12°
Φ	1.10	1.20	1.30

Rev.02 202510



BR

050N03

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Note

BR	Company Code
050N03	Product Type Code
****:	Lot No. Code, code change with Lot No.